

## 2-Input Positive-AND Gate

Description
This single 2-input positive-AND gate is designed for 1.65V to 5.5V V <sub>CC</sub> operation.
The HM74LVC1G08 device performs the Boolean function Y=A <sub>X</sub> B in positive logic.
The CMOS device has high output drive while maintaining low static power dissipation over a broad V <sub>CC</sub> operating range.

Input voltage	$V_I$		0		5.5	V
Output voltage	$V_O$				$V_{CC}$	V
High- level input voltage	$V_{IH}$	$V_{CC} = 1.65V \text{ to } 1.95V$	0.65 $V_{CC}$			V
		$V_{CC} = 2.3V \text{ to } 2.7V$	1.7			
		$V_{CC} = 3V \text{ to } 3.6V$	2			
		$V_{CC} = 4.5V \text{ to } 5.5V$	0.7 $V_{CC}$			
Low- level input voltage	$V_{IL}$	$V_{CC} = 1.65V \text{ to } 1.95V$			0.35 $V_{CC}$	V
		$V_{CC} = 2.3V \text{ to } 2.7V$			0.7	
		$V_{CC} = 3V \text{ to } 3.6V$			0.8	
		$V_{CC} = 4.5V \text{ to } 5.5V$			0.3 $V_{CC}$	
High- level output current	$I_{OH}$	$V_{CC} = 1.65V$			-4	mA
		$V_{CC} = 2.3V$			-8	
		$V_{CC} = 3V$			-16	
		$V_{CC} = 3V$			-24	
		$V_{CC} = 4.5V$			-32	
Low- level output current	$I_{OL}$	$V_{CC} = 1.65V$			4	mA
		$V_{CC} = 2.3V$			8	
		$V_{CC} = 3V$			16	
		$V_{CC} = 3V$			24	
		$V_{CC} = 4.5V$			32	
Input transition rise or fall rate	$\Delta T/\Delta V$	$V_{CC} = 1.8V \pm 0.15V, 2.5V \pm 0.2V$			20	ns/V
		$V_{CC} = 3.3V \pm 0.3V$			10	
		$V_{CC} = 5V \pm 0.5V$			5	
Operating temperature	$T_A$		-40		125	°C

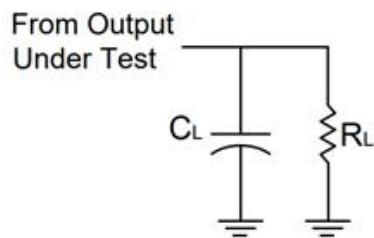
### Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Positive-going input threshold voltage	$V_{T+}$	$V_{CC} = 1.65V$	0.76		1.13	V
		$V_{CC} = 2.3V$	1.08		1.56	
		$V_{CC} = 3V$	1.48		1.92	
		$V_{CC} = 4.5V$	2.19		2.74	
		$V_{CC} = 5.5V$	2.65		3.33	
Negative-going input threshold voltage	$V_{T-}$	$V_{CC} = 1.65V$	0.35		0.59	V
		$V_{CC} = 2.3V$	0.56		0.88	
		$V_{CC} = 3V$	0.89		1.2	
		$V_{CC} = 4.5V$	1.51		1.97	
		$V_{CC} = 5.5V$	1.88		2.4	
Hysteresis Voltage	$\Delta V_T$	$V_{CC} = 1.65V$	0.36		0.64	V
		$V_{CC} = 2.3V$	0.45		0.78	
		$V_{CC} = 3V$	0.51		0.83	
		$V_{CC} = 4.5V$	0.58		0.93	
		$V_{CC} = 5.5V$	0.69		1.04	
High- level output voltage	$V_{OH}$	$V_{CC} = 1.65\sim 5.5V, I_{OH} = -100\mu A$	$V_{CC}-0.15$			V
		$V_{CC} = 1.65V, I_{OH} = -4mA$	1.2			
		$V_{CC} = 2.3V, I_{OH} = -8mA$	1.9			
		$V_{CC} = 3V, I_{OH} = -16mA$	2.4			
		$V_{CC} = 3V, I_{OH} = -24mA$	2.3			
		$V_{CC} = 4.5V, I_{OH} = -32mA$	3.8			
Low- level output voltage	$V_{OL}$	$V_{CC} = 1.65\sim 5.5V, I_{OL} = 100\mu A$			0.1	V
		$V_{CC} = 1.65V, I_{OL} = 4mA$			0.45	
		$V_{CC} = 2.3V, I_{OL} = 8mA$			0.3	
		$V_{CC} = 3V, I_{OL} = 16mA$			0.4	
		$V_{CC} = 3V, I_{OL} = 24mA$			0.55	
		$V_{CC} = 4.5V, I_{OL} = 32mA$			0.55	
Input leakage current	$I_I$	$V_{IN} = 5.5V$ or GND, $V_{CC} = 0\sim 5.5V$			$\pm 5$	$\mu A$
Power off leakage current	$I_{OFF}$	$V_{IN}$ or GND, $V_{CC} = 0\sim 5.5V$			$\pm 10$	$\mu A$
Quiescent supply current	$I_Q$	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$ , $V_{CC} = 1.65\sim 5.5V$			10	$\mu A$
Additional quiescent supply current per input pin	$\Delta I_Q$	$V_{CC} = 3\sim 5.5V$ , one input at $V_{CC}-0.6V$ , other input at $V_{CC}$ or GND			500	$\mu A$

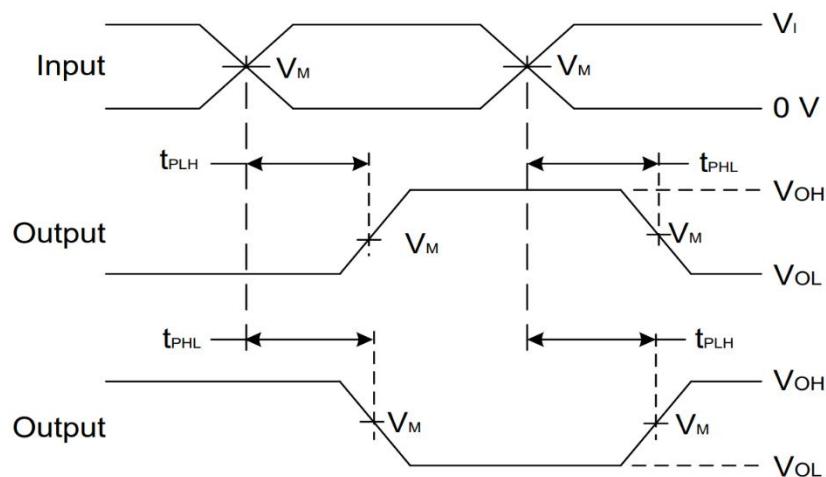
### Switching Characteristics

Parameter	Symbol	Conditions	Min	Typ	Max	Units	
Propagation delay from input(A or B) to output(Y)	$T_{PD}$	$V_{CC} = 1.8V \pm 0.15V$ ,	C <sub>L</sub> =15pF R <sub>L</sub> =1MΩ	2.8		9.9	ns
		$V_{CC} = 2.5V \pm 0.2V$		1.6		5.5	
		$V_{CC} = 3.3V \pm 0.3V$		1.5		4.6	
		$V_{CC} = 5V \pm 0.5V$		0.9		4.4	

Parameter Measurement Information



VCC	INPUTS		VM	CL	RL
	VI	t <sub>r</sub> /t <sub>f</sub>			
1.8V ± 0.15V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	15pF	1MΩ
2.5V ± 0.2V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	15pF	1MΩ
3.3V ± 0.3V	3V	≤2.5ns	1.5V	15pF	1MΩ
5V ± 0.5V	V <sub>CC</sub>	≤2.5ns	V <sub>CC</sub> /2	15pF	1MΩ



**Voltage Waveform Propagation Delay Times  
Inverting and Non Inverting Outputs**

Simplified Schematic

